QUADRUPLE 3-STATE BUFFERS OE LOW

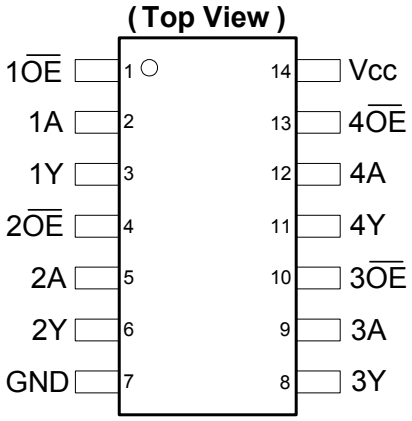
Description

The 74HCT125 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a high logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 4.5V to 5.5V.

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Pin Compatible with Low Power Schottky (LSTTL)
- Inputs Are TTL Voltage Level Compatible
- Sinks or Sources 4mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Pin Assignments



SO-14 / TSSOP-14

Applications

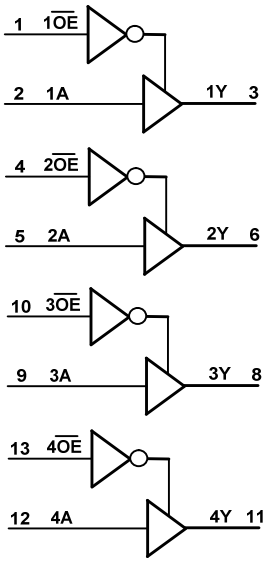
- General Purpose Logic
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Descriptions

Pin Number	Pin Name	Description
1	$1\overline{OE}$	Data Enable Input (active low)
2	1A	Data Input
3	1Y	Data Output
4	$2\overline{OE}$	Data Enable Input (active low)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	$3\overline{OE}$	Data Enable Input (active low)
11	4Y	Data Outp
12	4A	Data Input
13	$4\overline{OE}$	Data Enable Input (active low)
14	V_{CC}	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
V_I	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I_{IK}	Input Clamp Current V_I < -0.5V or Vi > V_{CC} +0.5V	±20	mA
I_{OK}	Output Clamp Current V_O < -0.5V or V_O > V_{CC} +0.5V	±20	mA
I_O	Continuous Output Current -0.5V < V_O V_{CC} +0.5V	+/-25	mA
I_{CC}	Continuous Current Through Vcc	50	mA
I_{GND}	Continuous Current Through GND	-50	mA
T_J	Operating Junction Temperature	-40 to +150	°C
T_{STG}	Storage Temperature	-65 to +150	°C
P_{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
5. Input Voltage cannot exceed V_{CC} to the extent the Maximum clamp current is exceeded.

Recommended Operating Conditions (Note 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage		4.5	5.5	V
V_I	Input Voltage		0	V_{CC}	V
V_O	Output Voltage		0	V_{CC}	V
Δt/ΔV	Input Transition Rise or Fall Rate	V_{CC} = 4.5V to 5.5V		500	ns/V
T_A	Operating Free-Air Temperature		-40	+125	°C

Note: 6. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V_{CC}	T_A = -40°C to +85°C		T_A = -40°C to +125°C		Unit
				Min	Max	Min	Max	
V_{IH}	High-Level Input Voltage		4.5V to 5.5V	2.0		2.0		V
V_{IL}	Low-Level Input Voltage		4.5V to 5.5V		0.8		0.8	V
V_{OH}	High-Level Output Voltage	I_{OH} = -20μA	4.5V	4.4		4.4		V
		I_{OH} = -4mA	4.5V	3.84		3.70		
V_{OL}	Low-Level Output Voltage	I_{OL} = 20μA	4.5V		0.1		0.1	V
		I_{OL} = 4.0mA	4.5V		0.33		0.4	
I_{OZ}	Z State Leakage Current	V_O = 0 to 5.5V	5.5V		± 5.0		± 10	μA
I_I	Input Current	V_I =GND to 6.0V	6.0V		± 1		± 1	μA
I_{CC}	Supply Current	V_I = GND or V_{CC}, I_O = 0	6.0V		20		40	μA
ΔI_{CC}	Additional Supply Current	One Input at V_{CC} –2.1V Other Pins at V_{CC} or GND	4.5V to 5.5V		675		735	μA

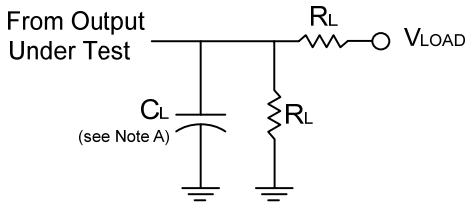
Switching Characteristics

Symbol	Parameter	Test Conditions	V_{CC}	T_A = +25°C			-40°C to +85°C	-40°C to +125°C	Unit
				Min	Typ	Max	Max	Max	
t_{PD}	Propagation Delay A_N to Y_N	Figure 1 C_L = 50pF	4.5V	—	15	25	31	38	ns
t_{EN}	Enable Time OE_N to Y_N			—	15	28	35	42	ns
t_{DIS}	DisableTime OE_N to Y_N			—	15	25	31	38	ns
t_t	Transition Time			—	5	12	15	18	ns

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

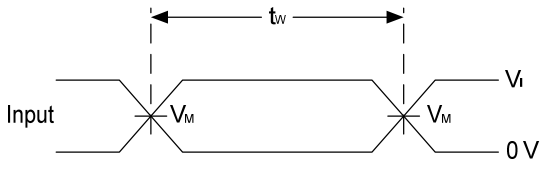
Parameter		Test Conditions	V_{CC} = 5.5V	Unit
			Typ	
C_{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	24	pF
C_I	Input Capacitance	V_I = V_{CC} – or GND	3.5	pF

Parameter Measurement Information

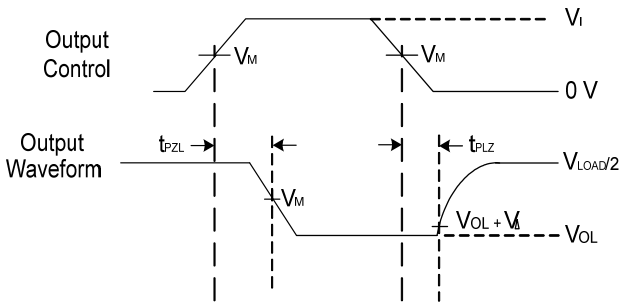


TEST	Condition
t_{PLZ} (see Notes D and E)	Vload
t_{PZL}(see Notes D and F)	Vload

V_{CC}	Inputs		V_M	V_{LOAD}	C_L	R_L	$V\Delta$
	V_I	t_r/t_f					
4.5V	1.5V	≤6ns	3.0V	2 X V_{CC}	50pF	2KΩ	10% of V_{CC}



Voltage Waveform
Pulse Duration

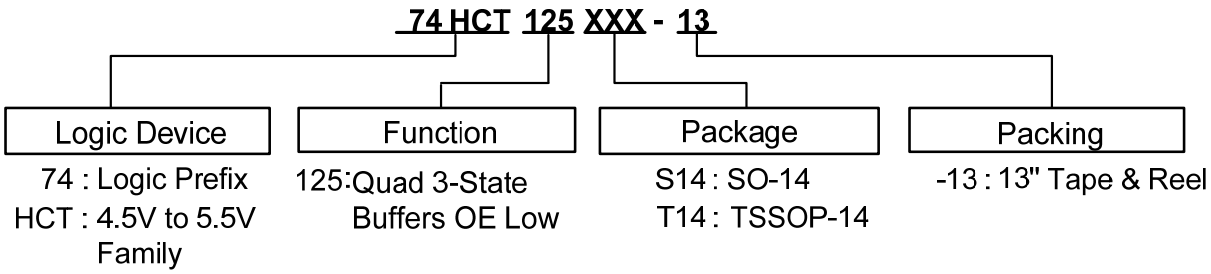


Voltage Waveform
Propagation Delay Times

Notes:
A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 1 MHz
C. The inputs are measured one at a time with one transition per measurement.
D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD}
E. t_{PZL} is measured at V_M.
D. t_{PLZ} is measured at V_{OL} +V_Δ
F. A Thevenin equivalent load may be used in place of V_{CC} X 2 and resistor divider

Figure 1 Load Circuit and Voltage Waveforms

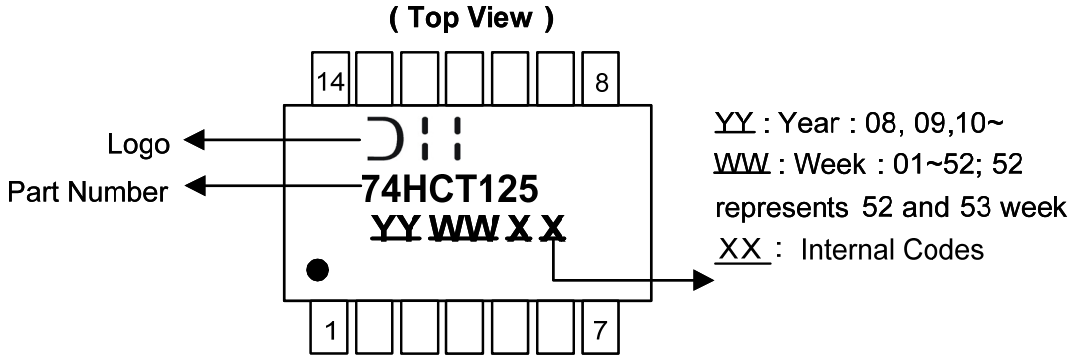
Ordering Information



Device	Package Code	Packaging	7" Tape and Reel	
			Quantity	Part Number Suffix
74HCT125S14-13	S14	SO-14	2500/Tape & Reel	-13
74HCT125T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14

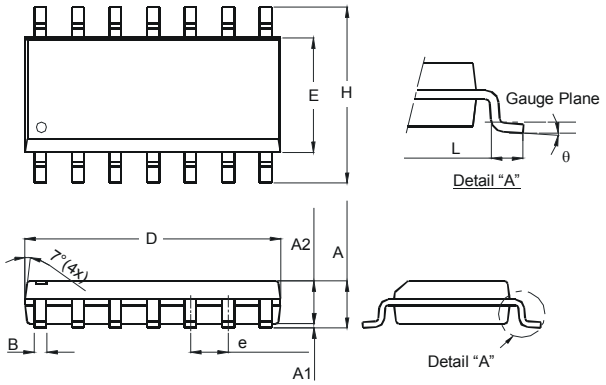


Part Number	Package
74HCT125S14	SO-14
74HCT125T14	TSSOP-14

Package Outline Dimensions (All dimensions in mm.)

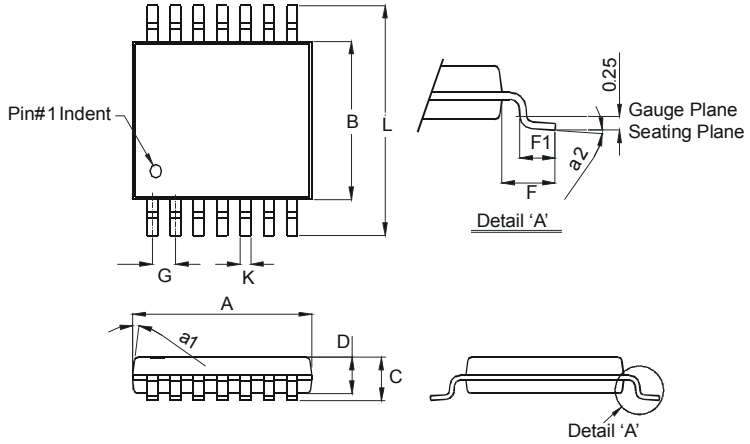
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



SO-14		
Dim	**Min**	**Max**
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14

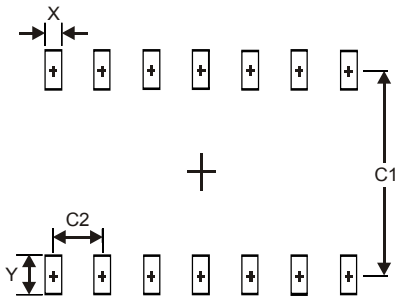


TSSOP-14		
Dim	**Min**	**Max**
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		

Suggested Pad Layout

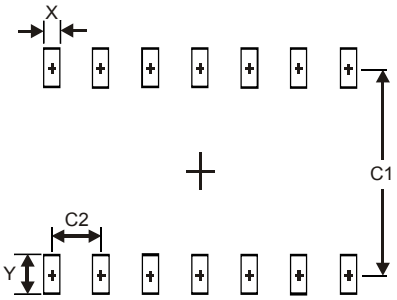
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

www.diodes.com

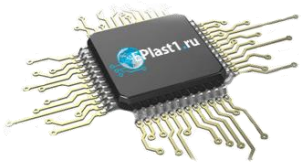
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)
Факс: 8 (812) 320-02-42
Электронная почта: org@eplast1.ru
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.